

An experimentally-validated multi-scale materials, process and device modelling & design platform enabling non-expert access to open innovation in the Organic and Large Area Electronics Industry (MUSICODE)

Grand Agreement: 953187

Project Start Date: 01/01/2021

Project Duration: 48 months

Deliverable 2.6

Report on modelling hybrid perovskite materials

Date: 18-05-2023



This project has received funding from the European Union's Horizon 2020 Research and Innovation Programme under the Call DT-NMBP-11-2020 "Open Innovation Platform for Materials Modelling"

Project co-funded by the European Commission within Horizon 2020 Research and Innovation Programme				
Dissemination Level				
PU	Public			
PP	Restricted to other programme participants (including the Commission Service)			
RE	Restricted to a group specified by the consortium (including the Commission Services)			
CO	Confidential, only for members of the consortium (excluding the Commission Services)	х		

Deliverable author(s): Cameron Underwood, Dimitar Kutsarov and Ravi Silva (USUR)

Contributors

Draft Revisions:v1.1 16/05/2023 submitted to coordinatorv2.0 18/05/2023 review, final edit, and approval by coordinator

Copyright

@ Copyright 2021-2024 The MUSICODE Consortium

Consisting of Coordinator:	University of Ioannina (UoI)	Greece
Partners:	Karlsruhe Institute of Technology (KIT)	Germany
	University of Surrey (SURREY)	UK
	Aristotle University of Thessaloniki (AUTh)	Greece
	Czech Technical University in Prague (CVUT)	Czechia
	Fluxim AG (FLUXIM)	Switzerland
	TinniT Technologies GmbH (TINNIT)	Germany
	Granta design LTD (GRANTA)	UK
	Esteco SPA (ESTECO)	Italy
	Organic Electronic Technologies (OET)	Greece
	Apeva SE (APEVA)	Germany
	AIXTRON SE (AIXTRON)	Germany

This document may not be copied, reproduced, or modified in whole or in part for any purpose without written permission from the MUSICODE Consortium. In addition to such written permission to copy, reproduce, or modify this document in whole or part, an acknowledgment of the authors of the document and all applicable portions of the copyright notice must be clearly referenced.

All Rights reserved.



This project has received funding from the European Union's Horizon 2020 Research and Innovation Programme under the Call DT-NMBP-11-2020 "Open Innovation Platform for Materials Modelling"

"The European Commission support for the production of this publication does not constitute an endorsement of the contents which reflects the views only of the authors, and the Commission cannot be held responsible for any use which may be made of the information contained therein."

Contents

Publishable summary	
1. Introduction	5
1.1 Purpose of this document	10
2. Methodology and results	11
2.1 Density Functional Theory (DFT) Calculations & Other Relevant Software Packages	11
2.1.1 2D Perovskite Solar Absorber Layers	11
2.2 Results	15
2.2.1 2D Perovskite Solar Absorber Layers	15
3. Discussion	22
3.1 Achievements	22
3.2 Risks	22
3.3 Next steps	22
4. Conclusions	22
References:	23

Publishable summary

There is no doubt that Perovskite-based Photovoltaics (PV) will enter the PV marketplace very soon. This originates from their unique properties, such as band gap tunability and high absorbance coefficient, making them suitable for indoor applications, vacuum- and/or solution processability, high power conversion efficiency (PCEs), and many more. While a non-certified PCE of only 2.8% was reported in 2009 for perovskite solar cells (PSCs), the current certified PCE record for a single junction PSCs is 25.8%. Notably, this PCE is higher than the highest reported for a single junction multi-crystalline PV (24.4%), which is the most wide-spread silicon-based PV technology nowadays. Recently (stand April 2023), KAUST reported a certified PCEs of 33.2% for a tandem perovskite/Si device, which again is higher than recently reported PCE for a Si-based multijunction device (32.9%). Clearly, PSCs show an unprecedented PV technology development step in terms of PCE. Giant improvement leaps have also been achieved in terms of the operation stability of the PSCs and reports of a successful passing of IEC testing standards such as ISOS-L2 and ISOS-D3 have been shown.

Although various material systems have been studied, theoretically there are many possible two-dimensional perovskite systems of the form $PEA_2Ge_{1-x}Sn_xI_4$, where x = 0, 0.25, 0.5, 0.75 and 1 which have not been explored yet. Hence, in this report we use plane-wave DFT calculations to gather insight into theoretical properties of such perovskite systems. We show that these systems show a nonlinear trend of band gap as a function of Sn content, where $PEA_2Ge_{1-x}Sn_xI_4$ shows a minimum at a predicted x = 0.725 and a band gap of 1.945 eV. The behaviour of the electronic structure is consistent between the Pb-Sn and Ge-Sn systems, although there is a difference in the band gap bowing; this is attributed to the smaller ionic radius of Ge as compared to Pb and is thus a measure that can be used to control the nonlinear trend of band gap as a function of Sn content. Overall, this work contributes to the understanding of the electronic properties of perovskite systems and gives insights into the possibility of fabricating Ge-Sn based Ruddlesden-Popper perovskites in future electronic devices.